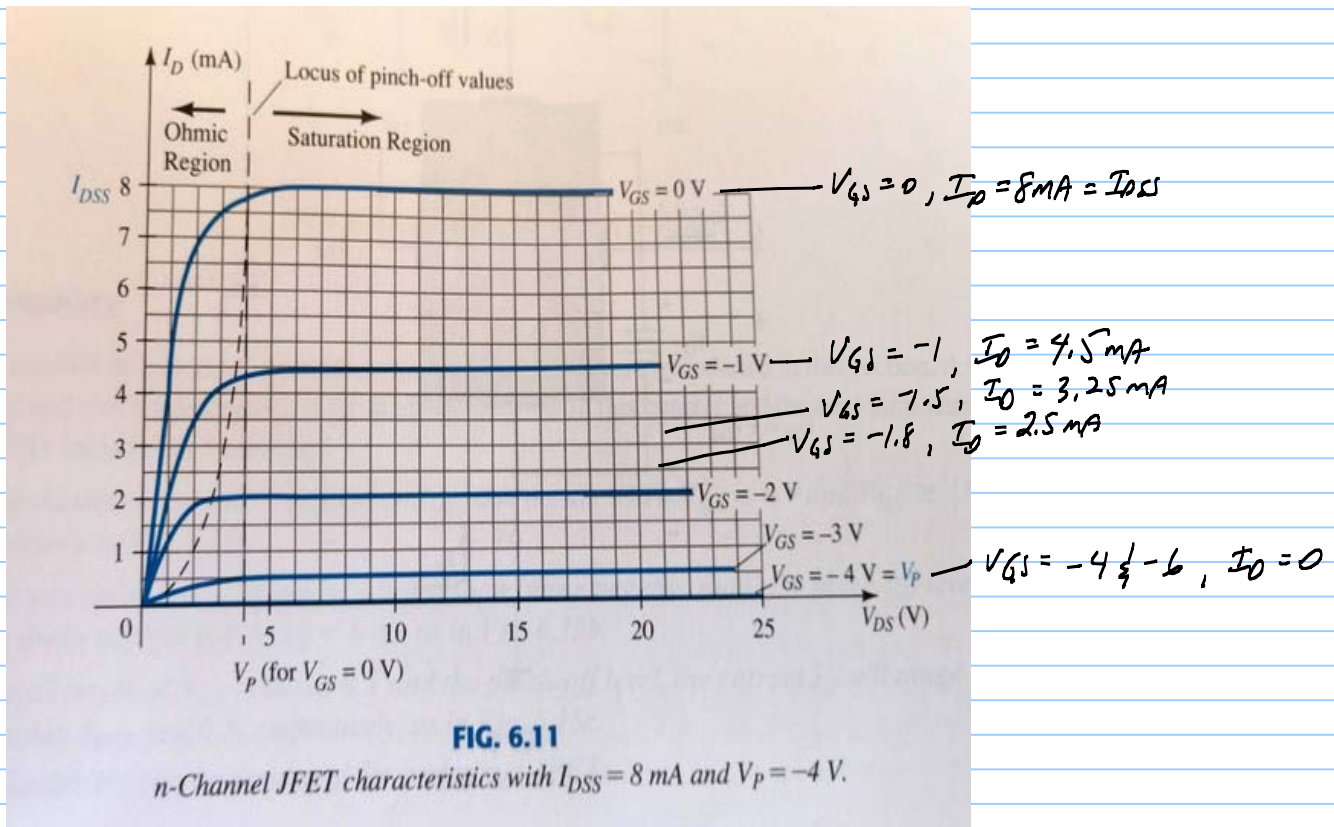


Chapter 6 #2, 8, 11a, 30, 32, 39

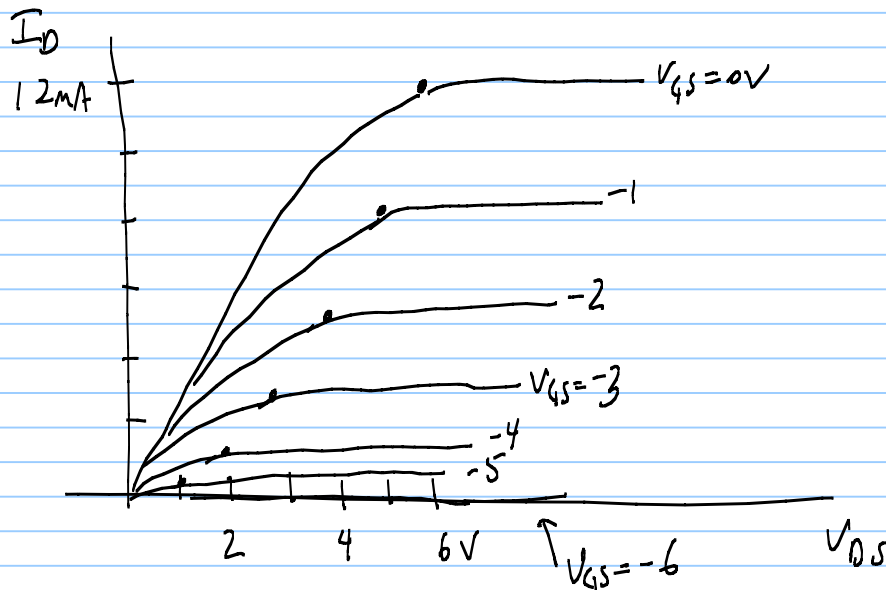
Note Title

8/11/2018

- 2) Using the characteristic curve below, determine I_D when $V_{GS} = 0, -1, -1.5, -1.8, -4, -6$ when $V_{DS} > V_P$.



- 8) Given $I_{DSS} = 12 \text{ mA}$ and $|V_P| = 6 \text{ V}$, sketch the probable distribution of characteristic curves for the JFET (similar to 6.11 above)



$$V_{GS} = 0 \text{ \& } I_D = I_{DSS} = 12 \text{ mA}$$

$$V_{GS} \leq V_P = -6, I_D = 0$$

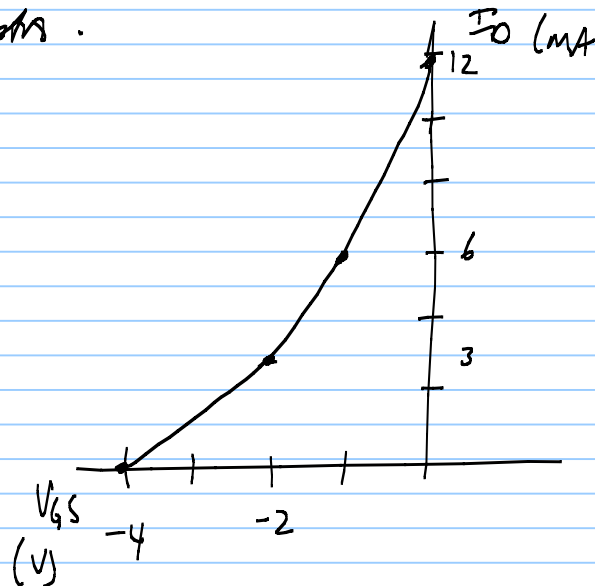
Using Shockley's equation

V_{GS}	I_D
-1 V	8.33 mA
-2 V	5.33 mA
-3 V	3 mA
-4 V	1.33 mA
-5 V	0.33 mA

11a) Given $I_{DSS} = 12\text{mA}$ and $V_p = -4$, sketch the transfer characteristics for the JFET transistor.

Use table

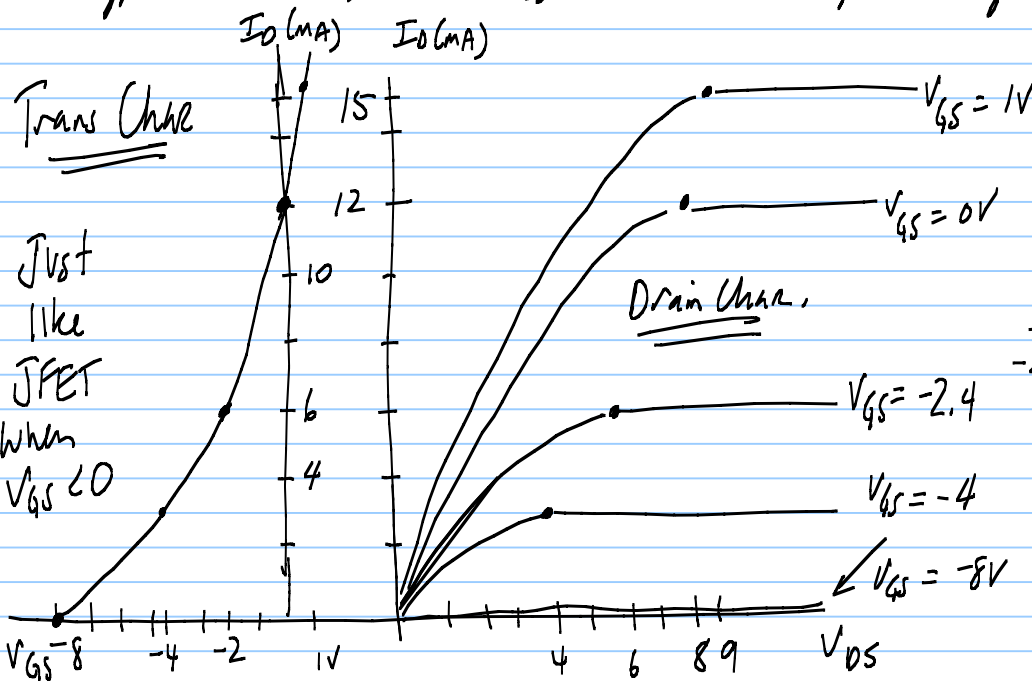
V_{GS}	I_D
0	$I_{DSS} = 12\text{mA}$
$-1.2 = 0.3V_p$	$I_{DSS}/2 = 6\text{mA}$
$-2 = 0.5V_p$	$I_{DSS}/4 = 3\text{mA}$
$-4 = V_p$	0



Can also generate table using

$$I_D = I_{DSS} \left(1 - \frac{V_{GS}}{V_p} \right)^2$$

30) Sketch the transfer and drain characteristics of an N-channel depletion type MOSFET with $I_{DSS} = 12\text{mA}$ and $V_p = -8\text{V}$ for the range of $V_{GS} = -V_p$ to $V_{GS} = 1\text{V}$



$$I_D = I_{DSS} \left(1 - \frac{V_{GS}}{V_p} \right)^2$$

V_{GS}	I_{DSS}
0	$I_{DSS}/4 = 3\text{mA}$
$-4 = -0.5V_p$	$I_{DSS}/2 = 6\text{mA}$
$-8 = -V_p$	$I_{DSS} = 12\text{mA}$
1V	15.19 mA

$I_D = 12\text{mA} \left(1 - \frac{1}{-8} \right)^2$
 $= 15.19\text{mA}$

unlike JFET, V_{GS} of N channel MOSFET can go positive

32) Given $I_D = 4\text{mA}$ at $V_{GS} = -2\text{V}$, determine I_{DSS} if $V_P = -5\text{V}$.

$$I_D = I_{DSS} \left(1 - \frac{V_{GS}}{V_P}\right)^2$$

$$\frac{4\text{mA}}{\left(1 - \frac{-2}{-5}\right)^2} = I_{DSS} = 16.7\text{mA}$$

39) Given $K = 0.4 \times 10^{-3} \text{ A/V}^2$ and $I_{D(on)} = 3\text{mA}$ with $V_{GS(on)} = 4\text{V}$, determine V_T .

$$I_D = K (V_{GS} - V_T)^2 \quad 3\text{mA} = 0.4\text{m} (4 - V_T)^2$$

$$\sqrt{\frac{3\text{mA}}{0.4\text{m}}} = 4 - V_T = 2.74$$

$$V_T = 4 - 2.74 = \underline{\underline{1.26\text{V}}}$$